

Product Overview

FGD3325G2_F085: IGBT, 250V, 25A, 1.35V, 330mJ, EcoSPARK® II, N-Channel Ignition

For complete documentation, see the data sheet.

FGD3325G2_F085

Features

- SCIS Energy = 330mJ at $T_J = 250^{\circ}\text{C}$
- Logic Level Gate Drive
- Qualified to AEC Q101
- RoHS Compliant

Part Electrical Specifications

Product	Compliance	Status	$V_{ES}^{(BR)/C}$ Typ (V)	I_C Max (A)	$V_{CE(sat)}$ Typ (V)	V_f Typ (V)	E_{off} Typ (mJ)	E_{on} Typ (mJ)	T_{rr} Typ (ns)	I_r Typ (A)	Gate Charge Typ (nC)	Short Circuit Withstand (μs)	E_{AS} Typ (mJ)	P_D Max (W)	Co- Pack aged Diode	Pack age Type
FGD3325G2-F085	AEC Qualified PPAP Capable Pb-free Halide free	Active	250			-	-	-	1200	-	21	-	-	150	-	DPA K-3 / TO- 252-3

For more information please contact your local sales support at www.onsemi.com.

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